

Vishay General Semiconductor

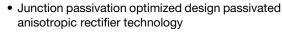
Surface Mount PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions



PRIMARY CHARACTERISTICS				
V_{WM}	10 V to 36 V			
V_{BR}	11.1 V to 44.2 V			
P _{PPM} (10 x 1000 μs)	3600 W			
P _{PPM} (10 x 10 000 μs)	2800 W			
P_{D}	5 W			
I _{FSM}	500 A			
T_J max.	175 °C			
Polarity	Uni-directional			
Package	DO-218AB			

FEATURES





 T_J = 175 °C capability suitable for high reliability and automotive requirement

RoHS

- · Available in uni-directional polarity only
- Low leakage current
- · Low forward voltage drop
- High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AB

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("X" denotes revision code e.g. A, B, ..., revision code only applicable for part number with \pm 5 % tolerance)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation	with 10/1000 µs waveform	Б	3600	W		
	with 10/10 000 µs waveform	P _{PPM}	2800	VV		
Power dissipation on infinite heats	P _D	5.0	W			
Peak pulse current with 10/1000 µ	I _{PPM} ⁽¹⁾	See next table	Α			
Peak forward surge current 8.3 m	I _{FSM}	500	Α			
Operating junction and storage te	T _J , T _{STG}	-55 to +175	°C			

Note

⁽¹⁾ Non-repetitive current pulse at T_A = 25 °C



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DEVICE TYPE	BREAKDOWN VOLTAGE V _{BR} (V)		TEST CURRENT I _T	STAND-OFF VOLTAGE V _{WM}	MAXIMUM REVERSE LEAKAGE	MAXIMUM REVERSE LEAKAGE AT V _{WM}	MAX. PEAK PULSE CURRENT AT 10/1000 µs WAVEFORM	MAXIMUM CLAMPING VOLTAGE
	MIN.	MAX.	(mA)	(V)	AT V _{WM} I _D (μΑ)	T _J = 175°C I _D (μΑ)	(A)	AT I _{PPM} V _C (V)
SM5S10	11.1	13.6	5.0	10.0	15	250	191	18.8
SM5S10A	11.1	12.3	5.0	10.0	15	250	212	17.0
SM5S11	12.2	14.9	5.0	11.0	10	150	179	20.1
SM5S11A	12.2	13.5	5.0	11.0	10	150	198	18.2
SM5S12	13.3	16.3	5.0	12.0	10	150	164	22.0
SM5S12A	13.3	14.7	5.0	12.0	10	150	181	19.9
SM5S13	14.4	17.6	5.0	13.0	10	150	151	23.8
SM5S13A	14.4	15.9	5.0	13.0	10	150	167	21.5
SM5S14	15.6	19.1	5.0	14.0	10	150	140	25.8
SM5S14A	15.6	17.2	5.0	14.0	10	150	155	23.2
SM5S15	16.7	20.4	5.0	15.0	10	150	134	26.9
SM5S15A	16.7	18.5	5.0	15.0	10	150	148	24.4
SM5S16	17.8	21.8	5.0	16.0	10	150	125	28.8
SM5S16A	17.8	19.7	5.0	16.0	10	150	138	26.0
SM5S17	18.9	23.1	5.0	17.0	10	150	118	30.5
SM5S17A	18.9	20.9	5.0	17.0	10	150	130	27.6
SM5S18	20.0	24.4	5.0	18.0	10	150	112	32.2
SM5S18A	20.0	22.1	5.0	18.0	10	150	123	29.2
SM5S20	22.2	27.1	5.0	20.0	10	150	101	35.8
SM5S20A	22.2	24.5	5.0	20.0	10	150	111	32.4
SM5S22	24.4	29.8	5.0	22.0	10	150	91	39.4
SM5S22A	24.4	26.9	5.0	22.0	10	150	101	35.5
SM5S24	26.7	32.6	5.0	24.0	10	150	84	43.0
SM5S24A	26.7	29.5	5.0	24.0	10	150	93	38.9
SM5S26	28.9	35.3	5.0	26.0	10	150	77	46.6
SM5S26A	28.9	31.9	5.0	26.0	10	150	86	42.1
SM5S28	31.1	38.0	5.0	28.0	10	150	72	50.1
SM5S28A	31.1	34.4	5.0	28.0	10	150	79	45.4
SM5S30	33.3	40.7	5.0	30.0	10	150	67	53.5
SM5S30A	33.3	36.8	5.0	30.0	10	150	74	48.4
SM5S33	36.7	44.9	5.0	33.0	10	150	61	59.0
SM5S33A	36.7	40.6	5.0	33.0	10	150	68	53.3
SM5S36	40.0	48.9	5.0	36.0	10	150	56	64.3
SM5S36A	40.0	44.2	5.0	36.0	10	150	62	58.1

Note

For all types maximum V_F = 2.0 V at I_F = 100 A measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses
per minute maximum

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Typical thermal resistance, junction to case	$R_{ heta JC}$	1.0	°C/W		

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SM5S10AHE3/2D ⁽¹⁾	2.505	2D	750	13" diameter plastic tape and reel, anode towards the sprocket hole		
SM5S10AHE3_A/I (1)	2.505	1	750	13" diameter plastic tape and reel, anode towards the sprocket hole		

Note

(1) AEC-Q101 qualified

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

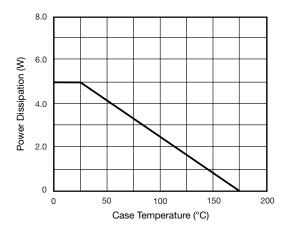


Fig. 1 - Power Derating Curve

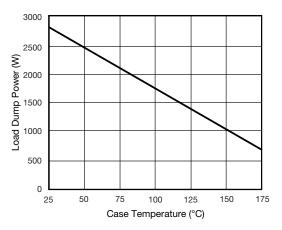


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

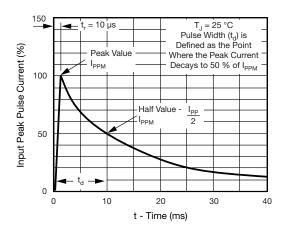


Fig. 3 - Pulse Waveform

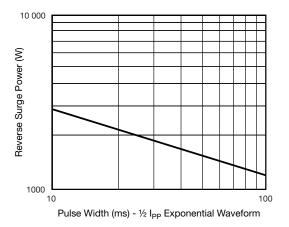


Fig. 4 - Reverse Power Capability

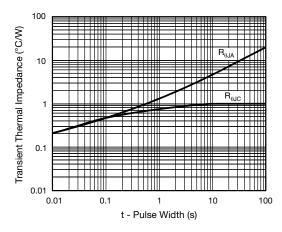
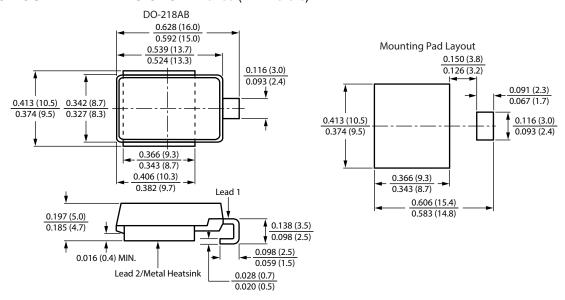


Fig. 5 - Typical Transient Thermal Impedance



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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